Analog Power AM4874N

N-Channel 30-V (D-S) MOSFET

Key Features:

- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

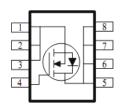
Typical	Applications	
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- White LED boost converters
- · Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
30	11 @ V _{GS} = 10V	16.8	
	12 @ V _{GS} = 4.5V	16.1	







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	±20	V	
Continuous Dusin Commenta	T _A =25°C		16.8		
Continuous Drain Current ^a	T _A =70°C	I _D	14.2	Α	
Pulsed Drain Current ^b		I _{DM}	100		
Continuous Source Current (Diode Conduction) a		Is	5.1	Α	
Dower Dissipation ^a	T _A =25°C		3.1	W	
Power Dissipation ^a	T _A =70°C		2.2	VV	
Operating Junction and Storage Temperature Range		T _J , T _{sta}	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter			Maximum	Units	
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{\theta JA}$	40	°C/W	
Maximum Junction-to-Ambient	Steady State	IΛθJA	80		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Electrical Characteristics

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	lana	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
Zero Gate Voltage Brain Gurrent	I _{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	30			Α
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 13.4 \text{ A}$			11	mΩ
Dialii-30dice Oil-Resistance	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 10.8 \text{ A}$			12	11122
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 13.4 \text{ A}$		15		S
Diode Forward Voltage	V_{SD}	$I_S = 2.6 \text{ A}, V_{GS} = 0 \text{ V}$		0.74		V
		Dynamic				
Total Gate Charge	Q_g	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		15		
Gate-Source Charge	Q_{gs}	$I_{DS} = 13 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 13.4 \text{ A}$		5.6		nC
Gate-Drain Charge	Q_gd	ID = 10.4 A		7.0		
Turn-On Delay Time	t _{d(on)}	$V_{DS} = 15 \text{ V}, R_{L} = 1.2 \Omega,$		6		
Rise Time	t _r	$V_{DS} = 13 \text{ V}, K_L - 1.2 \Omega,$ $I_D = 13.4 \text{ A},$		15		ne
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		38		ns
Fall Time	t _f	VGEN = 10 V, NGEN = 0 12		20		
Input Capacitance	C _{iss}			1456		
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		231		pF
Reverse Transfer Capacitance	C_{rss}			198		

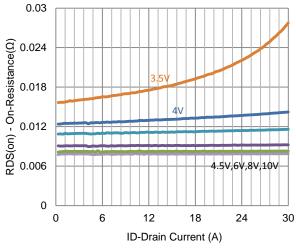
Notes

- Pulse test: PW <= 300us duty cycle <= 2%.
- Guaranteed by design, not subject to production testing. b.

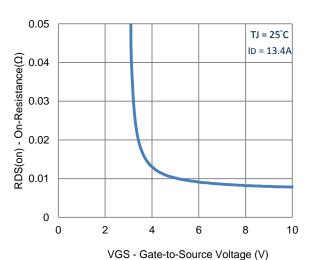
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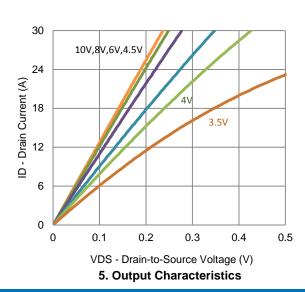
Typical Electrical Characteristics



1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



TJ = 25°C

40

40

40

40

20

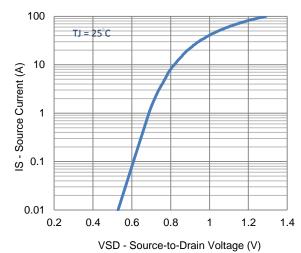
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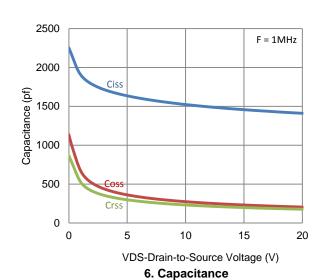
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VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

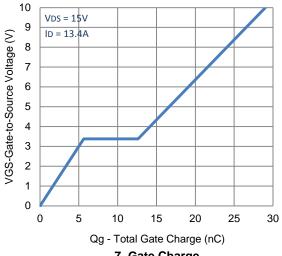


4. Drain-to-Source Forward Voltage



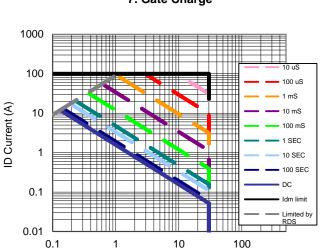
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Typical Electrical Characteristics

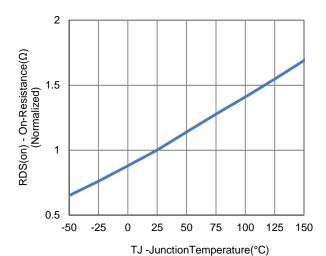


7. Gate Charge

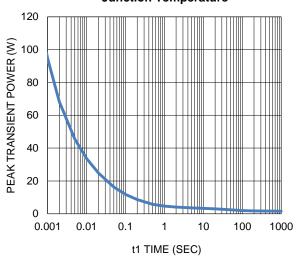
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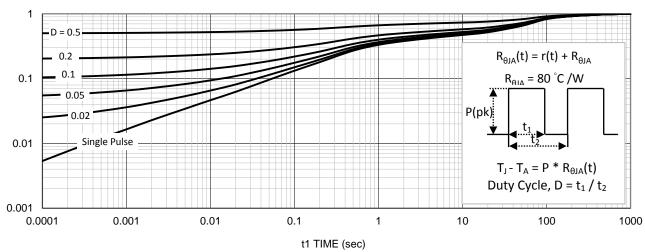
VDS Drain to Source Voltage (V) 9. Safe Operating Area



8. Normalized On-Resistance Vs **Junction Temperature**



10. Single Pulse Maximum Power Dissipation

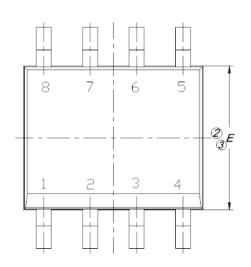


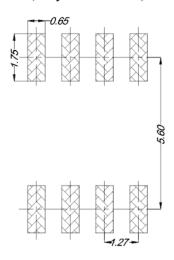
11. Normalized Thermal Transient Junction to Ambient

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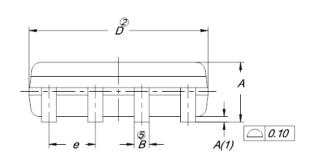
Package Information

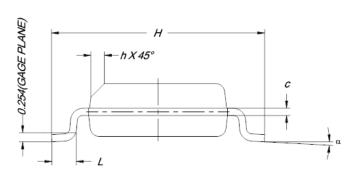
Land Pattern (Only for Reference)





DIM	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
Α	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
Н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		





Note:

- 1. All Dimension Are In mm.
- Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- 3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- Dimension "B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of "B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.